NSN 5961-01-075-0426

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View Online at https://aerobasegroup.com/nsn/5961-01-075-0426 **Inclosure Material:** Metal **Overall Length:** Between 0.200 inches and 0.265 inches **Overall Diameter:** Between 0.470 inches and 0.500 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact-darlington connected **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 60.0 collector to emitter voltage/static/base open and 60.0 collector to base voltage, dc and 50.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 4.00 amperes source cutoff current **Power Rating Per Characteristic:** 50.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 1 case and 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: